Quad 2-input NAND gate

Rev. 5 — 30 April 2021

Product data sheet

1. General description

The 74ALVC00 is a quad 2-input NAND gate.

Schmitt trigger action on all inputs makes the device tolerant of slow rise and fall times.

2. Features and benefits

- Wide supply voltage range from 1.65 V to 3.6 V
- 3.6 V tolerant inputs/outputs
- CMOS low power consumption
- Direct interface with TTL levels (2.7 V to 3.6 V)
- Power-down mode
- Latch-up performance exceeds 250 mA
- Complies with JEDEC standards:
 - JESD8-7 (1.65 V to 1.95 V)
 - JESD8-5 (2.3 V to 2.7 V)
 - JESD8B (2.7 V to 3.6 V)
- ESD protection:
 - MM JESD22-A115-A exceeds 200 V
 - HBM JESD22-A114E exceeds 2000 V
- Multiple package options
- Specified from -40 °C to +85 °C

3. Ordering information

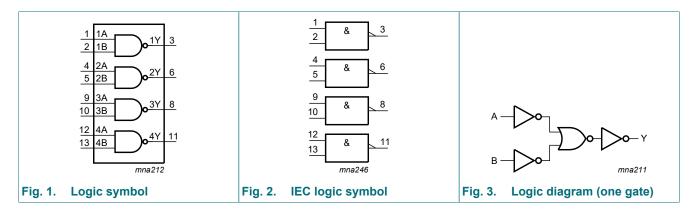
Table 1. Ordering information

| Type number | Package | | | | | | | | |
|-------------|-------------------|----------|--|----------|--|--|--|--|--|
| | Temperature range | Name | Description | Version | | | | | |
| 74ALVC00D | -40 °C to +85 °C | SO14 | plastic small outline package; 14 leads; body width 3.9 mm | SOT108-1 | | | | | |
| 74ALVC00PW | -40 °C to +85 °C | TSSOP14 | plastic thin shrink small outline package; 14 leads; body width 4.4 mm | SOT402-1 | | | | | |
| 74ALVC00BQ | -40 °C to +85 °C | DHVQFN14 | plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 × 3 × 0.85 mm | SOT762-1 | | | | | |



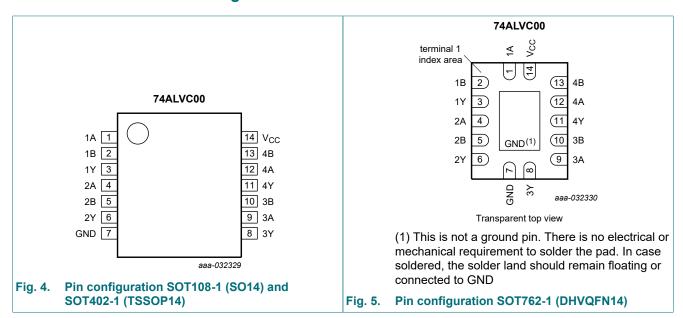
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4. Functional diagram



5. Pinning information

5.1. Pinning



5.2. Pin description

Table 2. Pin description

| Symbol | Pin | Description | |
|-----------------|--------------|----------------|--|
| 1A to 4A | 1, 4, 9, 12 | data input | |
| 1B to 4B | 2, 5, 10, 13 | data input | |
| 1Y to 4Y | 3, 6, 8, 11 | data output | |
| GND | 7 | ground (0 V) | |
| V _{CC} | 14 | supply voltage | |

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6. Functional description

Table 3. Function selection

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level; \ X = don't \ care$

| Input | Output | |
|-------|--------|----|
| nA | nB | nY |
| L | X | Н |
| X | L | Н |
| Н | Н | L |

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|------------------|-------------------------|--|-----|------|-----------------------|------|
| V _{CC} | supply voltage | | | -0.5 | +4.6 | V |
| I _{IK} | input clamping current | V _I < 0 V | | -50 | - | mA |
| VI | input voltage | | [1] | -0.5 | +4.6 | V |
| I _{OK} | output clamping current | V _O > V _{CC} or V _O < 0 V | | - | ±50 | mA |
| Vo | output voltage | output HIGH or LOW state | [1] | -0.5 | V _{CC} + 0.5 | V |
| | | output 3-state | | -0.5 | +4.6 | V |
| | | power-down mode; $V_{CC} = 0 V$ | | -0.5 | +4.6 | V |
| Io | output current | V _O = 0 V to V _{CC} | | - | ±50 | mA |
| I _{CC} | supply current | | | - | 100 | mA |
| I _{GND} | ground current | | | -100 | - | mA |
| T _{stg} | storage temperature | | | -65 | +150 | °C |
| P _{tot} | total power dissipation | T _{amb} = -40 °C to +85 °C | [2] | - | 500 | mW |

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

8. Recommended operating conditions

Table 5. Recommended operating conditions

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------------------|--|------|-----------------|------|
| V _{CC} | supply voltage | | 1.65 | 3.6 | V |
| VI | input voltage | | 0 | 3.6 | V |
| Vo | output voltage | output HIGH or LOW state | 0 | V _{CC} | V |
| | | output 3-state | 0 | 3.6 | V |
| | | power-down mode; V _{CC} = 0 V | 0 | 3.6 | V |
| T _{amb} | ambient temperature | in free air | -40 | +85 | °C |
| Δt/ΔV | input transition rise and fall rate | V _{CC} = 1.65 V to 2.7 V | 0 | 20 | ns/V |
| | | V _{CC} = 2.7 V to 3.6 V | 0 | 10 | ns/V |

^[2] For SOT402-1 (TSSOP14) package: Ptot derates linearly with 7.3 mW/K above 81 °C.

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9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | T _{amb} = | = -40 °C to | +85 °C | Unit |
|------------------|---------------------------|---|------------------------|-------------|------------------------|------|
| | | | Min | Typ[1] | Max | 1 |
| V _{IH} | HIGH-level input voltage | V _{CC} = 1.65 V to 1.95 V | 0.65 × V _{CC} | - | - | V |
| | | V _{CC} = 2.3 V to 2.7 V | 1.7 | - | - | V |
| | | V _{CC} = 2.7 V to 3.6 V | 2.0 | - | - | V |
| V _{IL} | LOW-level input voltage | V _{CC} = 1.65 V to 1.95 V | - | - | 0.35 × V _{CC} | V |
| | | V _{CC} = 2.3 V to 2.7 V | - | - | 0.7 | V |
| | | V _{CC} = 2.7 V to 3.6 V | - | - | 0.8 | V |
| V _{OH} | HIGH-level output voltage | $V_I = V_{IH}$ or V_{IL} | | | | |
| | | I _O = -100 μA; V _{CC} = 1.65 V to 3.6 V | V _{CC} - 0.2 | - | - | V |
| | | I _O = -6 mA; V _{CC} = 1.65 V | 1.25 | 1.51 | - | V |
| | | I _O = -12 mA; V _{CC} = 2.3 V | 1.8 | 2.10 | - | V |
| | | I_{O} = -18 mA; V_{CC} = 2.3 V | 1.7 | 2.01 | - | V |
| | | I _O = -12 mA; V _{CC} = 2.7 V | 2.2 | 2.53 | - | V |
| | | I_{O} = -18 mA; V_{CC} = 3.0 V | 2.4 | 2.76 | - | V |
| | | I _O = -24 mA; V _{CC} = 3.0 V | 2.2 | 2.68 | - | V |
| V _{OL} | LOW-level output voltage | V _I = V _{IH} or V _{IL} | | | | |
| | | I_{O} = 100 μ A; V_{CC} = 1.65 V to 3.6 V | - | - | 0.2 | V |
| | | I _O = 6 mA; V _{CC} = 1.65 V | - | 0.11 | 0.3 | V |
| | | I _O = 12 mA; V _{CC} = 2.3 V | - | 0.17 | 0.4 | V |
| | | I _O = 18 mA; V _{CC} = 2.3 V | - | 0.25 | 0.6 | V |
| | | I _O = 12 mA; V _{CC} = 2.7 V | - | 0.16 | 0.4 | V |
| | | I _O = 18 mA; V _{CC} = 3.0 V | - | 0.23 | 0.4 | V |
| | | I _O = 24 mA; V _{CC} = 3.0 V | - | 0.30 | 0.55 | V |
| I _I | input leakage current | V _{CC} = 3.6 V; V _I = 3.6 V or GND | - | ±0.1 | ±5 | μΑ |
| I _{OFF} | power-off leakage current | $V_{CC} = 0 \text{ V}; V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V}$ | - | ±0.1 | ±10 | μΑ |
| I _{CC} | supply current | $V_{CC} = 3.6 \text{ V}; V_{I} = V_{CC} \text{ or GND}; I_{O} = 0 \text{ A}$ | - | 0.2 | 20 | μΑ |
| Δl _{CC} | additional supply current | per input pin; $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V};$ $V_I = V_{CC} - 0.6 \text{ V};$ $I_O = 0 \text{ A}$ | - | 5 | 750 | μA |
| Cı | input capacitance | | - | 3.5 | - | pF |

^[1] All typical values are measured at V_{CC} = 3.3 V (unless stated otherwise) and T_{amb} = 25 °C.

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10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V). For test circuit, see Fig. 7.

| Symbol | Parameter | arameter Conditions | | | | T _{amb} = -40 °C to +85 °C | | | |
|-----------------------------------|-------------------------------|--|-----|-----|--------|-------------------------------------|----|--|--|
| | | | | Min | Typ[1] | Max | | | |
| t _{pd} propagation delay | | nA, nB to nY; see Fig. 6 | [2] | | | | | | |
| | | V _{CC} = 1.65 V to 1.95 V | | 1.0 | 2.8 | 4.4 | ns | | |
| | | V _{CC} = 2.3 V to 2.7 V | | 1.0 | 2.1 | 2.8 | ns | | |
| | | V _{CC} = 2.7 V | | 1.0 | 2.6 | 3.2 | ns | | |
| | | V _{CC} = 3.0 V to 3.6 V | | 1.0 | 2.1 | 3.0 | ns | | |
| C _{PD} | power dissipation capacitance | per gate; V_I = GND to V_{CC} ; V_{CC} = 3.3 V | [3] | - | 28 | - | pF | | |

- [1] Typical values are measured at T_{amb} = 25 °C
- [2] t_{pd} is the same as t_{PHL} and t_{PLH} .
- [3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

fo = output frequency in MHz;

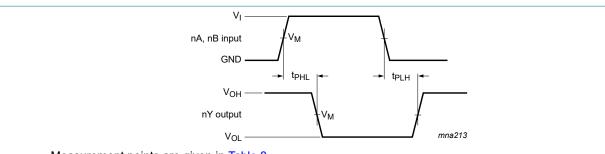
C_L = output load capacitance in pF;

V_{CC} = supply voltage in volt;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of the outputs.

10.1. Waveforms and test circuit



Measurement points are given in Table 8.

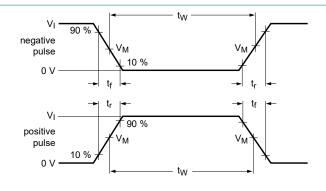
V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

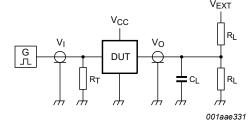
Fig. 6. Inputs nA, nB to output nY propagation delay times

Table 8. Measurement points

| Supply voltage V _{CC} | Input V _I | V _M |
|--------------------------------|----------------------|--------------------|
| 1.65 V to 1.95 V | Vcc | 0.5V _{CC} |
| 2.3 V to 2.7 V | V _{CC} | 0.5V _{CC} |
| 2.7 V | 2.7 V | 1.5 V |
| 3.0 V to 3.6 V | 2.7 V | 1.5 V |

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Test data is given in Table 9.

Definitions for test circuit:

 R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig. 7. Test circuit for measuring switching times

Table 9. Test data

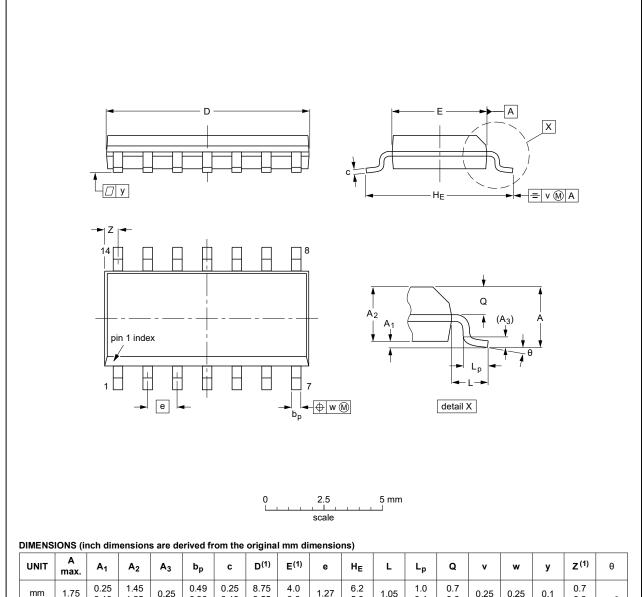
| Supply voltage V _{CC} | Input | | Load | | V _{EXT} | | | |
|--------------------------------|-----------------|---------------------------------|-------|----------------|-------------------------------------|-------------------------------------|-------------------------------------|--|
| | V _I | t _r , t _f | CL | R _L | t _{PLH} , t _{PHL} | t _{PLZ} , t _{PZL} | t _{PHZ} , t _{PZH} | |
| 1.65 V to 1.95 V | V _{CC} | ≤ 2.0 ns | 30 pF | 1 kΩ | open | 2 x V _{CC} | GND | |
| 2.3 V to 2.7 V | V _{CC} | ≤ 2.0 ns | 30 pF | 500 Ω | open | 2 x V _{CC} | GND | |
| 2.7 V | 2.7 V | ≤ 2.5 ns | 50 pF | 500 Ω | open | 6 V | GND | |
| 3.0 V to 3.6 V | 2.7 V | ≤ 2.5 ns | 50 pF | 500 Ω | open | 6 V | GND | |

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11. Package outline

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



| UNIT | A max. | A ₁ | A ₂ | A ₃ | b _p | С | D ⁽¹⁾ | E ⁽¹⁾ | е | HE | L | Lp | q | v | w | у | Z ⁽¹⁾ | θ |
|--------|-----------|-----------------------|----------------|-----------------------|----------------|------------------|------------------|------------------|------|----------------|-------|----------------|----------------|------|------|-------|------------------|----|
| mm | 1.75 | 0.25 0.10 | 1.45 1.25 | 0.25 | 0.49 0.36 | 0.25 0.19 | 8.75 8.55 | 4.0 3.8 | 1.27 | 6.2 5.8 | 1.05 | 1.0 0.4 | 0.7 0.6 | 0.25 | 0.25 | 0.1 | 0.7 0.3 | 8° |
| inches | 0.069 | 0.010 0.004 | 0.057 0.049 | 0.01 | | 0.0100 0.0075 | 0.35 0.34 | 0.16 0.15 | 0.05 | 0.244 0.228 | 0.041 | 0.039 0.016 | 0.028 0.024 | 0.01 | 0.01 | 0.004 | 0.028 0.012 | 0° |

Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

| OUTLINE | | REFER | EUROPEAN | ISSUE DATE | | |
|----------|--------|--------|----------|----------------|--|---------------------------------|
| VERSION | IEC | JEDEC | JEITA | JEITA PROJECTI | | ISSUE DATE |
| SOT108-1 | 076E06 | MS-012 | | | | 99-12-27 03-02-19 |

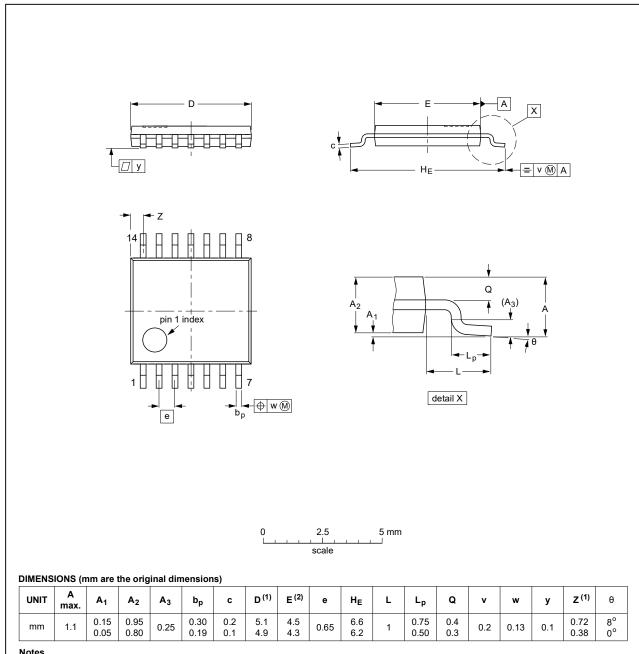
Fig. 8. Package outline SOT108-1 (SO14)

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TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

| OUTLINE | | REFER | EUROPEAN | ISSUE DATE | | | |
|----------|-----|--------|----------|------------|------------|---------------------------------|--|
| VERSION | IEC | JEDEC | JEITA | | PROJECTION | ISSUE DATE | |
| SOT402-1 | | MO-153 | | | | 99-12-27 03-02-18 | |

Package outline SOT402-1 (TSSOP14)

Quad 2-input NAND gate

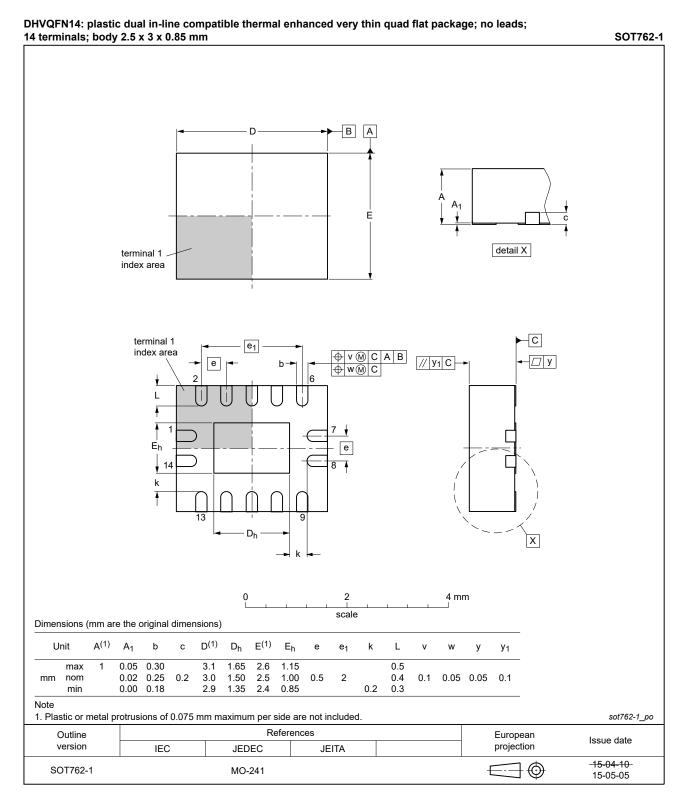


Fig. 10. Package outline SOT762-1 (DHVQFN14)

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12. Abbreviations

Table 10. Abbreviations

| Acronym | Description |
|---------|---|
| CMOS | Complementary Metal-Oxide Semiconductor |
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| HBM | Human Body Model |
| MM | Machine Model |
| TTL | Transistor-Transistor Logic |

13. Revision history

Table 11. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes | | |
|----------------|---|--|-------------------|--------------|--|--|
| 74ALVC00 v.5 | 20210430 | Product data sheet | - | 74ALVC00 v.4 | | |
| Modifications: | | Section 2: Reference to JESD36 removed. Table 4: Derating values for P_{tot} total power dissipation updated (errata). | | | | |
| 74ALVC00 v.4 | 20200921 | Product data sheet | - | 74ALVC00 v.3 | | |
| Modifications: | Nexperia. Legal texts have Table 4: Deratin | The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Table 4: Derating values for P_{tot} total power dissipation have been updated. Package outline drawing of SOT762-1 (Fig. 10) updated. | | | | |
| 74ALVC00 v.3 | 20140516 | Product data sheet | - | 74ALVC00 v.2 | | |
| | The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. Legal texts have been adapted to the new company name where appropriate. | | | | | |
| | Legal texts have | e been adapted to the new co | ompany name where | appropriate. | | |
| 74ALVC00 v.2 | Legal texts have 20030514 | Product specification | ompany name where | 74ALVC00 v.1 | | |

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14. Legal information

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| Document status [1][2] | Product status [3] | Definition |
|--------------------------------|-----------------------|---|
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 NL17SH02P5T5G
 74AUP2G00RA3-7

 NLV74HC02ADTR2G
 NLX1G332CMUTCG
 NL17SG86P5T5G
 NL17SZ05P5T5G
 NLV74VHC00DTR2G